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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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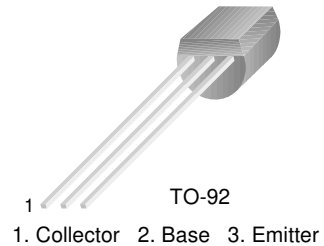
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



BC307/308/309

Switching and Amplifier Applications

- Low Noise: BC309



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage		
	: BC307	-50	V
	: BC308/309	-30	V
V_{CEO}	Collector-Emitter Voltage		
	: BC307	-45	V
	: BC308/309	-25	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current (DC)	-100	mA
P_C	Collector Power Dissipation	500	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage : BC307 : BC308/309	$I_C = -2\text{mA}, I_B = 0$	-45 -25			V V
BV_{CES}	Collector-Emitter Breakdown Voltage : BC307 : BC308/309	$I_C = -10\mu\text{A}, V_{BE} = 0$	-50 -30			V V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu\text{A}, I_C = 0$	-5			V
I_{CES}	Collector Cut-off Current : BC307 : BC308/309	$V_{CE} = -45\text{V}, V_{BE} = 0$ $V_{CE} = -25\text{V}, V_{BE} = 0$		-2 -2	-15 -15	nA nA
h_{FE}	DC Current Gain	$V_{CE} = -5\text{V}, I_C = -2\text{mA}$	120		800	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$ $I_C = -100\text{mA}, I_B = -5\text{mA}$		-0.5	-0.3	V V
$V_{BE}(\text{sat})$	Collector-Base Saturation Voltage	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$ $I_C = -100\text{mA}, I_B = -5\text{mA}$		-0.7 -0.85		V V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE} = -5\text{V}, I_C = -2\text{mA}$	-0.55	-0.62	-0.7	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -5\text{V}, I_C = -10\text{mA}, f = 50\text{MHz}$		130		MHz
C_{ob}	Output Capacitance	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$			6	pF
C_{ib}	Input Capacitance	$V_{EB} = -0.5\text{V}, I_C = 0, f = 1\text{MHz}$		12		pF
NF	Noise Figure : BC307/308 : BC309 : BC309	$V_{CE} = -5\text{V}, I_C = -0.2\text{mA},$ $R_G = 2\text{K}\Omega, f = 1\text{KHz}$ $V_{CE} = -5\text{V}, I_C = -0.2\text{mA}$ $R_G = 2\text{K}\Omega, f = 30\sim 15\text{KHz}$			10 4 4	dB dB dB

 h_{FE} Classification

Classification	A	B	C
h_{FE}	120 ~ 220	180 ~ 460	380 ~ 800

Typical Characteristics

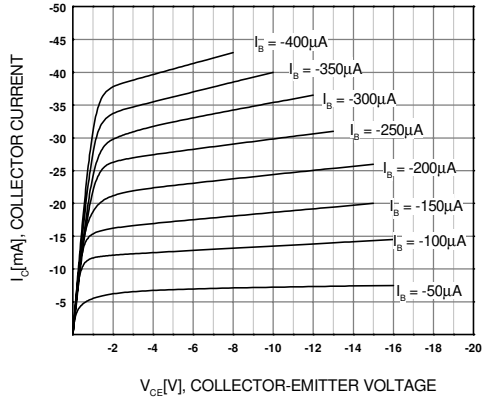


Figure 1. Static Characteristic

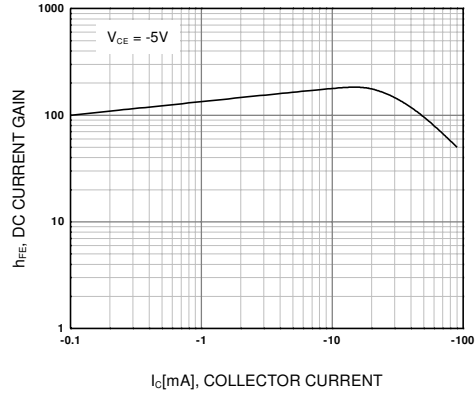


Figure 2. DC current Gain

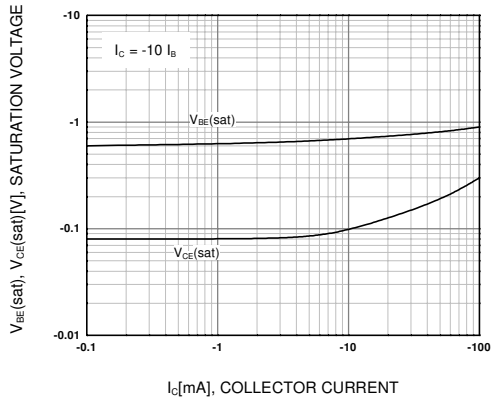


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

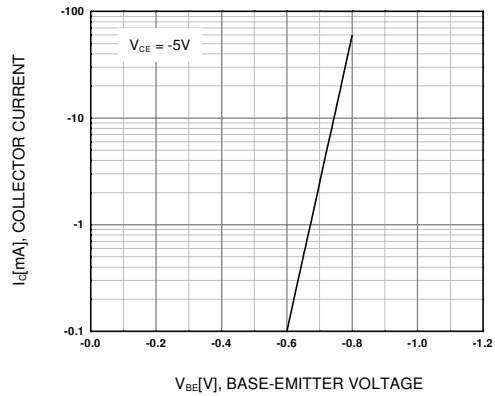


Figure 4. Base-Emitter Capacitance

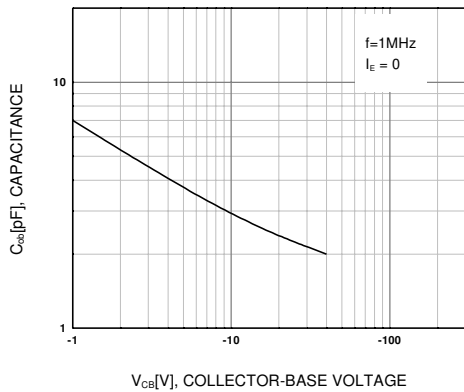


Figure 5. Collector Output Capacitance

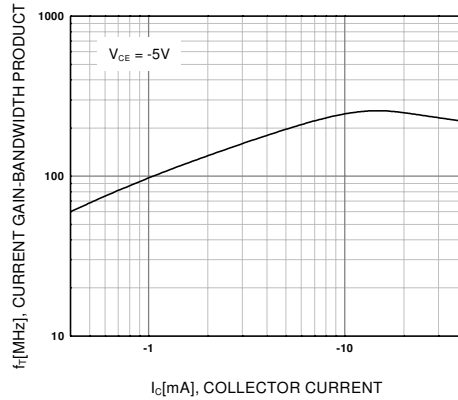
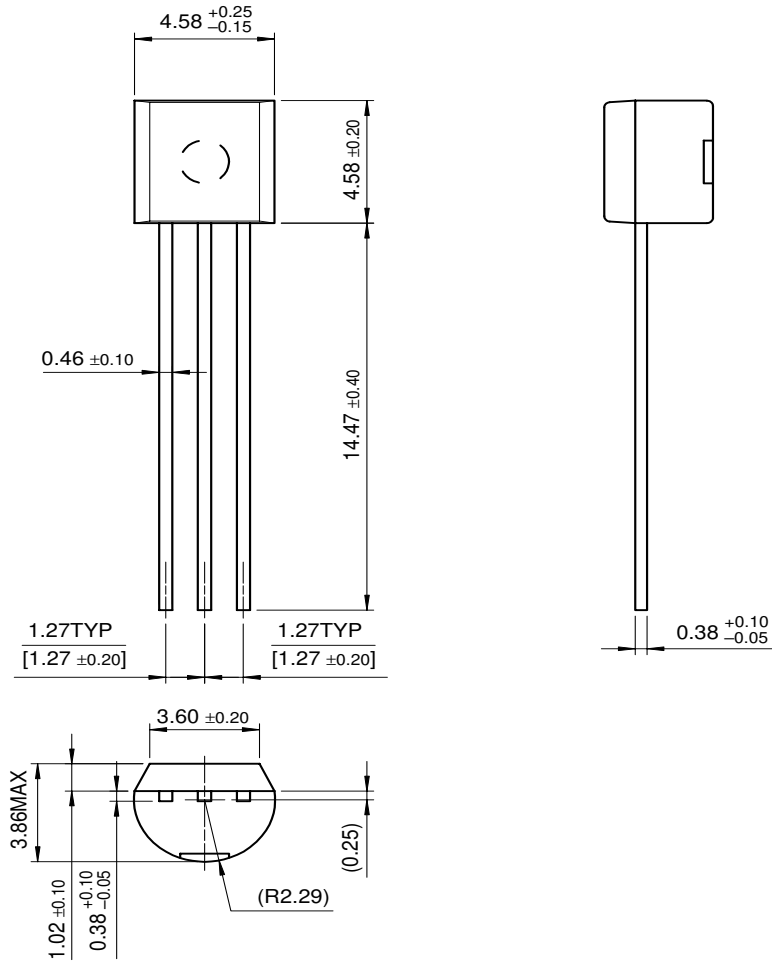


Figure 6. Current Gain Bandwidth Product

Package Dimensions

BC307/308/309

TO-92



Dimensions in Millimeters

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CoolFET™	FAST _r ™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOL™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C™	OCX™	RapidConfigure™	UHC™
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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